

LC-TOSA7WWDxxGEO-x

Technical Specification of 25G CWDM MQW-DFB Laser Diode Module
(Transmitter Optical Sub-assembly)

Features

- ◆ Coaxial Package
- ◆ MQW-DFB laser Diode
- ◆ Very Low Threshold Current
- ◆ Capable of transmission up to 25Gb/s per channel
- ◆ Operating Case temperature: -40°C to +90°C
- ◆ RoHS Compliant Products Available

Applications

- ◆ SFP28
- ◆ High speed Data Communication

Ordering information (Standard version ^{*Note1})

Part No.	Pin Type	Power(mW)	Wavelength(nm)	Isolator
LC-TOSA7WWD0831GEO-5	LD-Pin-20	0.5~0.9	1310	Single Stage
LC-TOSA7WWD0831GEO-6	LD-Pin-20	0.5~0.8	1310	Single Stage
LC-TOSA7WWD0831GEO-8	LD-Pin-20	0.4~0.8	1310	Single Stage

*Note1: For more ordering information, please refer the nomenclature and contact EOPTOLINK sales.

Absolute maximum ratings ^{*Note2}

Parameter	Symbol	Ratings	Unit
Storage temperature	T _{STG}	-40~+90	°C
Operating case temperature	T _{OP}	-40~+90	°C
Forward current (LD)	I _{FLD}	100	mA
Reverse voltage (LD)	V _{RLD}	2	V
Reverse voltage (MPD)	V _{RMPD}	20	V
Reverse current (MPD)	I _{RMPD}	2	mA
Soldering temperature (<10s)	S _{TEMP}	260	°C

*Note2: Exceeding any one of these values may destroy the device immediately.

Electrical and optical characteristics

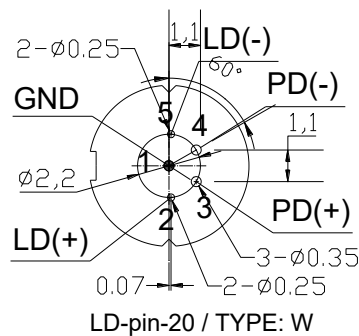
(Pf=1.5mW, SMF(9/125μm), Tc=+25°C, unless otherwise noted.)

Parameter	Symbol	Min	Typ	Max	Unit	Condition
Threshold current	I _{th}	—	8	15	mA	CW
Fiber Coupling Power	P _f	0.4	—	0.99	mW	CW, I _f =I _{th} +30mA
Operating voltage	V _f	—	1.3	1.7	V	CW,
Slope Efficiency	S _e	0.02	—	0.05	mW/mA	CW, Average(I _{th} to I _{th} +30mA)
Peak wavelength	λ _p	1262.5	1270	1277.5	nm	CW
		1282.5	1290	1297.5		
		1302.5	1310	1317.5		
		1322.5	1330	1337.5		
		1342.5	1350	1357.5		
		1362.5	1370	1377.5		
Wavelength/Temperature	dλ/dT	—	0.09	—	nm/°C	Coefficient T=-40~+90°C
Side mode suppression ratio	SMSR	35	40	—	dB	CW
Bandwidth	BW	21	—	—	GHz	at-3dB
Rise time	t _r	—	—	13	ps	I _b =I _{th} , 20-80%, ER=6dB
Fall time	t _f	—	—	20	ps	I _b =I _{th} , 80-20%, ER=6dB
Tracking error	ΔP _f	-1.5	—	1.5	dB	I _m hold(@P _f =1.5mW CW, T _c =-40~+90°C
Monitor current ^{*Note3}	I _{mo}	0.1	—	1.0	mA	CW, V _{RP} =5V T _C =-40~+90°C
Monitor dark current	I _d	—	—	10	nA	V _{RP} =5V
Monitor capacitance	C	—	10	20	pF	V _{RP} =5V, f=1MHz
Connector repeatability	—	-1	—	1	dB	
Optical Isolation	—	30	—	—	dB	Single Stage

*Note3:I_{mo} test error ≤±10%

Pin Assignment

TYPE: 20



Obtaining Document

You can visit our website:

<http://www.eoptolink.com>

Or contact Eoptolink Technology Inc., Ltd. listed at the end of the documentation to get the latest documentation.

Revision History

Verision	Initiated	Reviewed	Approved	Revision History	Release Date
Va-1	Yinchun.Zhao	James.liu	Vincent.yu		2019.12.25
Va-2	Yinchun.Zhao	James.liu	Vincent.yu	Remove 15 power band, add F pin, add 1310±20nm, add TO type CO	2020.06.16
Va-3	Yinchun.Zhao	James.liu	Vincent.yu	The lower limit of power is adjusted from 0.6mW to 0.4 mw	2020.06.28
Va-4	Yinchun.Zhao	James.liu	Vincent.yu	Update Threshold current	2020.12.03
Va-5	Yinchun.Zhao	James.liu	Vincent.yu	Update power range	2021.01.08

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